

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013

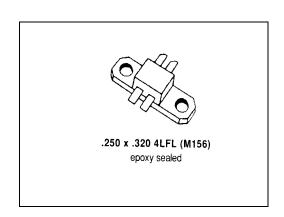
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# **MS1579**

# RF & MICROWAVE TRANSISTORS TV LINEAR APPLICATIONS

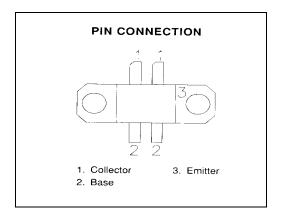
#### Features

- 470 860 MHz
- 25 VOLTS
- CLASS A OPERATION
- INTERNAL INPUT MATCHING
- P<sub>OUT</sub> = 14 WATTS
- $G_P = 8.5 \text{ dB MINIMUM}$
- COMMON EMITTER CONFIGURATION



### DESCRIPTION:

The MS1579 is a gold metallized, epitaxial silicon NPN transistor designed for Class A, UHF and Band IV, V television transmitters applications. Diffused emitter ballast resistors ensure long term reliability under Class A linear operation.



# ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	45	V
V <sub>CEO</sub>	Collector-Emitter Voltage	25	V
$V_{\scriptscriptstyle{EBO}}$	Emitter-Base Voltage	4.0	V
P <sub>DISS</sub>	Power Dissipation	65	W
Ic	Device Current	5.2	Α
<b>T</b> J	Junction Temperature	+200	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

### Thermal Data

R <sub>TH(J-C)</sub> I nermal Resistance Junction-case 2.5 °C/W	R <sub>TH(J-C)</sub>	Thermal Resistance Junction-case	2.5	°C/W
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MS1579

# ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

## **STATIC**

Symbol	Test Conditions			Value		
Syllibol	rest Conditions	Min.	Typ.	Max.	Unit	
BV <sub>CBO</sub>	$I_c = 20 \text{ mA}$	$I_E = 0 \text{ mA}$	45			V
BV <sub>CEO</sub>	$I_c = 40 \text{ mA}$	$I_B = 0 \text{ mA}$	25			V
BV <sub>EBO</sub>	I <sub>E</sub> = 5 mA	$I_c = 0 \text{ mA}$	3.0			V
HFE	V <sub>CE</sub> = 20 V	$I_c = 0.5 A$	10		200	

## **DYNAMIC**

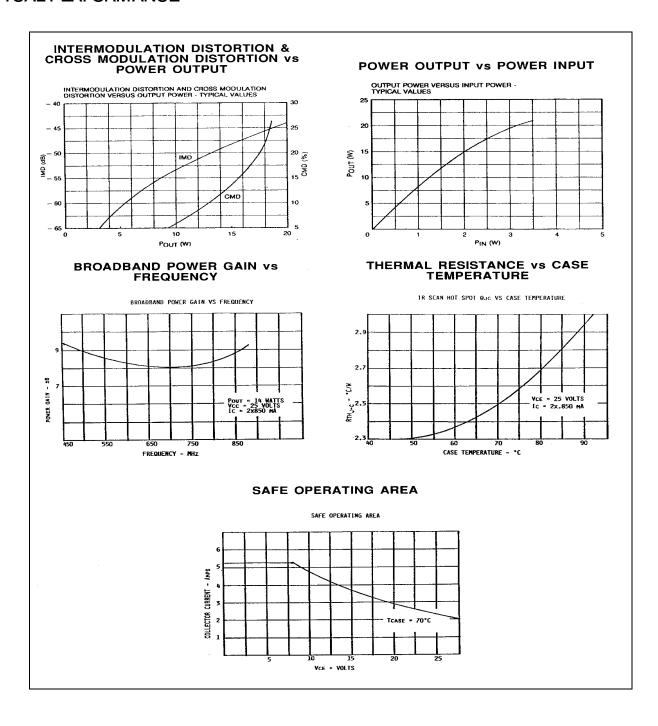
Symbol	Test Conditions			Value			
Symbol			Min.	Typ.	Max.	Unit	
P <sub>out</sub>	f = 845 MHz	$P_{IN} = 2.0$	$V_{CE} = 25 \text{ V}$	14			w
G₽	P <sub>OUT</sub> = 14 W	$P_{IN} = 2.0$	$V_{CE} = 25 \text{ V}$	8.5			dB
IMD <sub>3</sub>	P <sub>OUT</sub> = 14 W	P <sub>IN</sub> = 2.0	V <sub>CE</sub> = 25 V		-47		dBc
Сов	f =1 MHz	V <sub>CB</sub> = 25 V				20	pf

Conditions:  $V_{CE} = 25 \text{ V}$   $I_{CQ} = 2 \text{ x } 850 \text{ mA}$ 



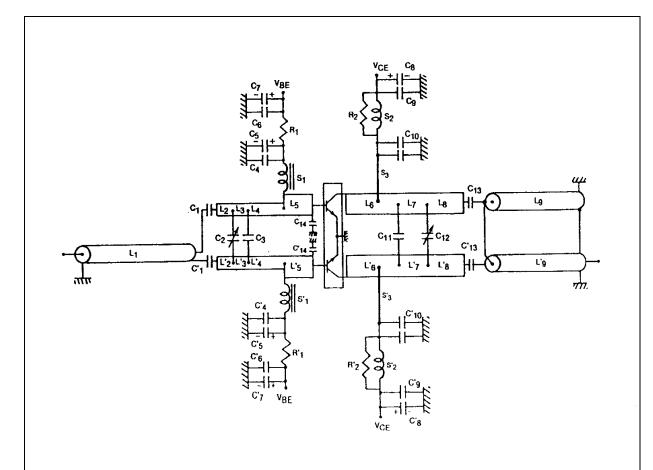


### TYPICAL PERFORMANCE





### TEST CIRCUIT



C1, C1, C1, C3, C3 :  $50\Omega$  Printed Transmission Line Length 3mm L4, L3 :  $50\Omega$  Printed Transmission Line Length 9.5mm C2 : 4.5pF Adjustable Johanson L5, L5 :  $39\Omega$  Printed Transmission Line Length 7mm C3 : 4.7pF, ATC 100A L6, L6 :  $39\Omega$  Printed Transmission Line Length 15mm C4, C4, C6, C9, C9, C9, L7, L7 :  $39\Omega$  Printed Transmission Line Length 8mm

C4, C4, C6, C6, C9, C9, C10, C10, C10: 100pF, ATC 100A + 1nF LCC Chip + 10nF LCC Chip L8, L'8: 39\(\Omega\) Printed Transmission Line Length 10mm

C5, C'5 :  $4.7\mu\text{F}$ , 25V, Tantalum Capacitor C7, C'7 :  $10\mu\text{F}$ , 25V, Tantalum Capacitor R1, R'1 :  $4.7\Omega$ , 1/2W C8, C'8 :  $22\mu\text{F}$ , 35V, Tantalum Capacitor R2, R'2 :  $1207\Omega$ , 1/2W C11 : 4.7pf, ATC 100A

C14, C'14: 22pF, ATC 100A S2, S'2: 5 Turns, Diameter Wire 0.5mm on 3mm l.D. S3, S'3: Diameter Wire 1.2mm, Length 12mm L1, L9, L'9:  $50\Omega$  Coaxial Wire Diameter 2.2mm, Length 29mm on

 $70\Omega$  Transmission Line Substrate: Teflon Glass 30Mils, Er = 2.55 .2, L'2 :  $50\Omega$  Printed Transmission Line Length 4mm





### PACKAGE MECHANICAL DATA

